

## Dual power Schottky diode

Rev.01 - 14 December 2021

**Product data sheet** 

### **1. General description**

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO220 plastic package.



## 2. Features and benefits

- Trench structure
- High junction temperature up to 150 °C
- Low forward voltage drop, negligible switching losses
- High efficiency

## **3. Applications**

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

### 4. Quick reference data

Symbol	Parameter	Conditions		luco		Unit
Symbol	Farameter	Conditions	Values			Unit
Absolute	maximum rating					
$V_{RRM}$	repetitive peak reverse voltage		150			V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; square-wave pulse; T <sub>mb</sub> ≤ 138 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	5		A	
I <sub>O(AV)</sub>	average output current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 138 °C; both diodes conducting	10		A	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V <sub>F</sub>	forward voltage	$I_F = 3 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$	-	0.71	-	V
		$I_F = 3 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 6$	-	0.57	-	V
		$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$	-	0.89	1	V
		$I_F = 5 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 6$	-	0.63	0.75	V
Ι <sub>R</sub>	reverse current	V <sub>R</sub> = 150 V; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 7; Fig. 8</u>	-	-	50	μA
		V <sub>R</sub> = 150 V; T <sub>j</sub> = 125 °C; per diode; <u>Fig. 7; Fig. 8</u>	-	-	15	mA

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## 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	K	cathode		
3	A2	anode 2		к К
mb	К	mounting base; connected to cathode		sym125

## 6. Ordering information

Table 3. Ordering information								
	Type number	Package	Orderable part number		Small packing		Package	
		name		method	quantity	version	issue date	
	WN3S10H150C	TO220	WN3S10H150CQ	Tube	50	SOT78	13-Jun-2008	

### 7. Marking

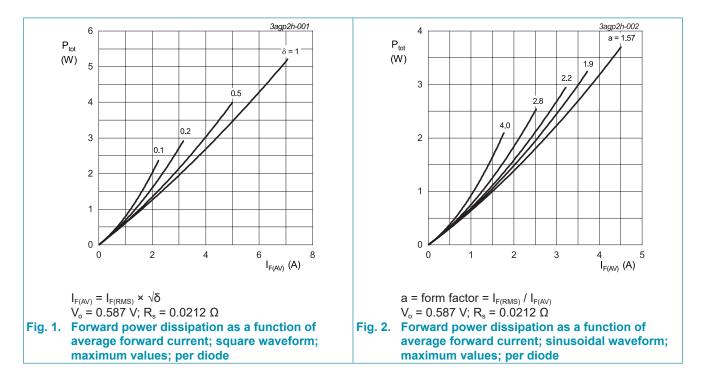
Table 4. Marking codes	
Type number	Marking codes
WN3S10H150C	WN3S 10H150C

## 8. Limiting values

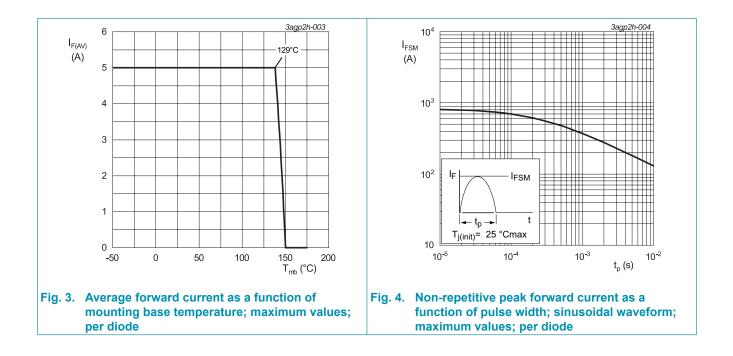
### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		150	V
V <sub>RWM</sub>	crest working reverse voltage		150	V
V <sub>R</sub>	reverse voltage	DC	150	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 138 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	5	A
I <sub>O(AV)</sub>	average output current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 138 °C; both diodes conducting	10	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	130	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	143	A
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>j</sub>	junction temperature		150	°C

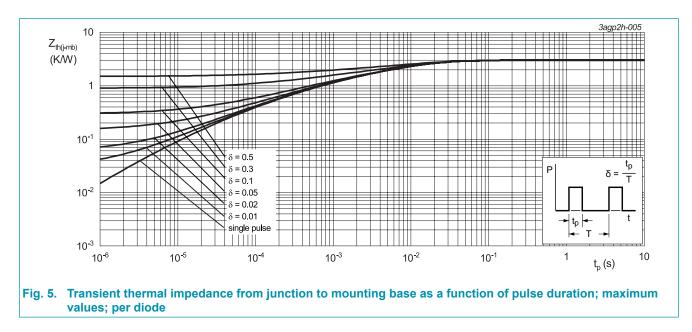


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## 9. Thermal characteristics

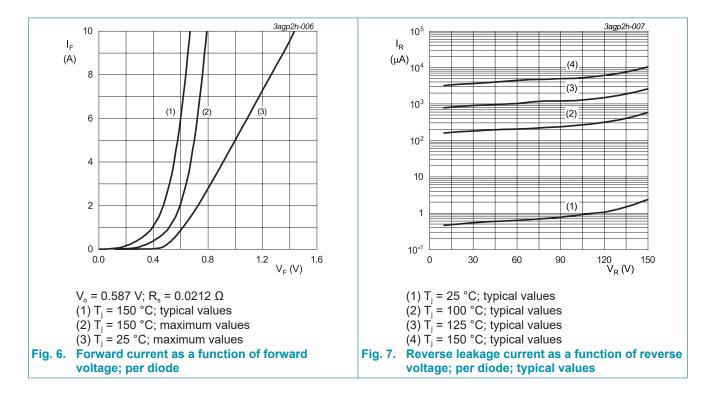
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>	-	-	3	K/W
		both diodes conducting	-	-	1.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



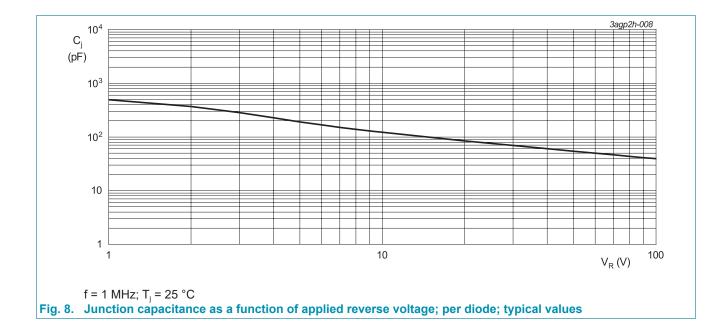
**Dual power Schottky diode** 

## **10. Characteristics**

Table 7. Ch	naracteristics						
Symbol	Parameter	eter Conditions		Min	Тур	Max	Unit
Static cha	aracteristics						
V <sub>F</sub>	forward voltage	$I_F = 3 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.71	-	V
		$I_F = 3 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.57	-	V
		$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.89	1	V
		$I_F = 5 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.63	0.75	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 150 V; T <sub>j</sub> = 25 °C; per diode; Fig. 7; Fig. 8		-	-	50	μA
		V <sub>R</sub> = 150 V; T <sub>j</sub> = 125 °C; per diode; Fig. 7; Fig. 8		-	-	15	mA

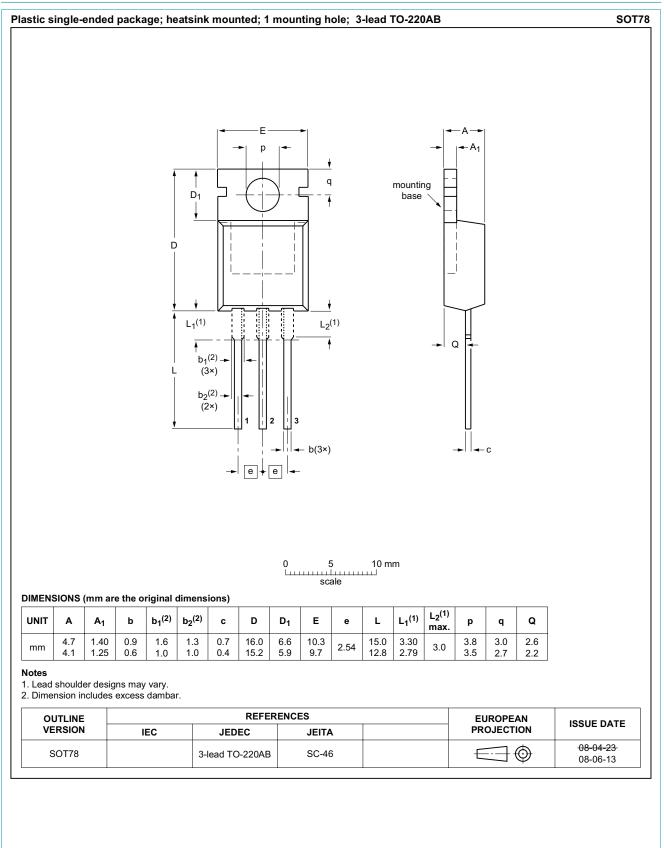


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**Dual power Schottky diode** 

## **11. Package outline**



#### **Dual power Schottky diode**

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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